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|---|--------------------------------|---|
|  | DMG1012TQ-7 | |
| | Hersteller-Teilenummer: | DMG1012TQ-7 |
|  | Hersteller / Marke: | Diodes Incorporated |
| | Teil der Beschreibung: | MOSFET NCH 20V 630MA SOT523 |
| <p>Image may be representation. See specs for product details.</p> | Datenblätter: |  DMG1012TQ-7.pdf |
| | RoHs Status: | Bleifrei / RoHS-konform |
| | Lagerzustand: | New original, 2005 pcs Stock Available. |
| | Liefern von: | Hong Kong |
| | Versandweg: | DHL/Fedex/TNT/UPS/EMS |

Spezifikationen

| | |
|---|---|
| Teilenummer | DMG1012TQ-7 |
| Hersteller | Diodes Incorporated |
| Beschreibung | MOSFET NCH 20V 630MA SOT523 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs , |
| Teilstatus | 2005 pcs Stock |
| Serie | Automotive, AEC-Q101 |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | SOT-523 |
| Supplier Device-Gehäuse | SOT-523 |
| Verlustleistung (max) | 280mW (Ta) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 20V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 630mA (Ta) |
| Rds On (Max) @ Id, Vgs | 400 mOhm @ 600mA, 4.5V |
| VGS (th) (Max) @ Id | 1V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 0.74nC @ 4.5V |
| Eingabekapazität (Ciss) (Max) @ Vds | 60.67pF @ 16V |
| Verpackung | Tape & Reel (TR) |













































DMG1012TQ-7 ist neu im Original, Suche DMG1012TQ-7 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DMG1012TQ-7 Diodes Incorporated mit Garantie und Vertrauen. Anfrage DMG1012TQ-7: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|--|---|--|
|  <p>DMG1012UW-7-F DIODES DIODES SOT-323</p> |  <p>DMG1012UW-7 Diodes Incorporated MOSFET N-CH 20V 1A SOT323</p> |  <p>DMG1013T D DMG1013T D</p> |  <p>DMG1012T D DMG1012T D</p> |
|  <p>DMG1012T-7-F DIODES DMG1012T-7-F DIODES</p> |  <p>DMG1012T-7 Diodes Incorporated MOSFET N-CH 20V 630MA SOT-523</p> |  <p>DMG1013UW-7 Diodes Incorporated MOSFET P-CH 20V 820MA SOT323</p> |  <p>DMG1013T-7-F DIODES DIODES SOT-523</p> |

heiße Teile

Mehr

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|--|---|--|--|--|
|  DMG1012T |  DMG1012T-7 |  DMG1012T-7-F | D DMG1012UW-7 |  DMG1013T |
|  DMG1013T-7 |  DMG1013TQ-7 | D DMG1013UW-7 |  DMG1013UWQ-7 |  DMG1016UDW-7 |
|  DMG1016V |  DMG1016V-7 |  DMG1023UV |  DMG1023UV-7 |  DMG1024UV |
| D DMG1024UV-7 |  DMG1026UV-7 |  DMG1029SV-7 |  DMG1029SV-7 |  DMG204B10R |
|  DMG2301L-7 |  DMG2301LK |  DMG2301LK-7 |  DMG2301U |  DMG2301U-7 |
|  DMG2301U-7-F |  DMG2302U | D DMG2302U-7 |  DMG2302U-7-F |  DMG2302UK |
|  DMG2302UK-7 | D DMG2302UQ |  DMG2302UQ-7 |  DMG2305UX |  DMG2305UX-13 |
|  DMG2305UX-7 |  DMG2305UXQ |  DMG2305UXQ-7 |  DMG2307L |  DMG2307L-7 |
|  DMG2307L-7-F |  DMG264H00R |  DMG301NU-13 | D DMG301NU-7 |  DMG302PU-7 |
|  DMG302PU-7 |  DMG3401LSN |  DMG3401LSN-7 |  DMG3401LSN-7-F |  DMG3402L-7 |

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